

IGBT Module

SK25GD126ET

Preliminary Data

Features

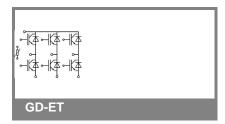
- Compact design
- · One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Ultrafast NPT technology IGBT
- CAL technology FWD
- Integrated NTC temperature sensor

Typical Applications*

Inverter

| Absolute Maximum Ratings $T_s = 25 ^{\circ}\text{C}$, unless otherwise specified | | | | | |
|---|---|-------------------------|--|------------------|-------|
| Symbol | Conditions | | | Values | Units |
| IGBT | | | | | |
| V_{CES} | T _j = 25 °C | | | 1200 | V |
| I _C | T _j = 150 °C | T _s = 25 °C | | 32 | Α |
| | | T_s = 80 °C | | 23 | Α |
| I _{CRM} | I _{CRM} = 2 x I _{Cnom} | | | 50 | А |
| V_{GES} | | | | ± 20 | V |
| t _{psc} | V_{CC} = 600 V; $V_{GE} \le 20$ V; $V_{CES} < 1200$ V | T _j = 125 °C | | 10 | μs |
| Inverse [| Diode | | | | |
| I _F | T _j = 150 °C | $T_s = 25 ^{\circ}C$ | | 28 | Α |
| | | T_s = 80 °C | | 19 | Α |
| I _{FRM} | I _{FRM} = 2 x I _{Fnom} | | | 50 | Α |
| Module | | | | | _ |
| I _{t(RMS)} | | | | | Α |
| T _{vj} | | | | -40 + 150 | °C |
| T _{stg} | | | | -40 + 125 | °C |
| V _{isol} | AC, 1 min. | | | 2500 | V |

| Characteristics $T_s =$ | | | 25 °C, unless otherwise specified | | | |
|-------------------------|---|---------------------------------|-----------------------------------|-----------|------|-----------|
| Symbol | Conditions | | min. | typ. | max. | Units |
| IGBT | | | | | | |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}$, $I_C = 1 \text{ mA}$ | | 5 | 5,8 | 6,5 | V |
| I _{CES} | V _{GE} = 0 V, V _{CE} = V _{CES} | T _j = 25 °C | | | 0,15 | mA |
| | | T _j = 125 °C | | | | mA |
| I _{GES} | V _{CE} = 0 V, V _{GE} = 20 V | T _j = 25 °C | | | 600 | nA |
| | | T _j = 125 °C | | | | nA |
| V _{CE0} | | T _j = 25 °C | | 1 | 1,2 | V |
| | | T _j = 125 °C | | 0,9 | | V |
| r_{CE} | V _{GE} = 15 V | T _j = 25°C | | 28 | 36 | mΩ |
| | | T _j = 125°C | | 44 | | $m\Omega$ |
| V _{CE(sat)} | I _{Cnom} = 25 A, V _{GE} = 15 V | | | 1,7 | 2,1 | V |
| | | $T_j = 125^{\circ}C_{chiplev.}$ | | 2,2 | | V |
| C _{ies} | | | | 1,8 | | nF |
| C _{oes} | $V_{CE} = 25, V_{GE} = 0 V$ | f = 1 MHz | | 0,095 | | nF |
| C _{res} | | | | 0,082 | | nF |
| t _{d(on)} | | | | 85 | | ns |
| Ţ, | $R_{Gon} = 25 \Omega$ | V _{CC} = 600V | | 30 | | ns |
| Ė _{on} | D -05.0 | I _C = 25A | | 3,3 | | mJ |
| ^L d(off) | $R_{Goff} = 25 \Omega$ | T _j = 125 °C | | 430 90 | | ns |
| t _f | | V _{GE} =±15V | | | | ns |
| E _{off} | | | | 3,1 | | mJ |
| $R_{th(j-s)}$ | per IGBT | | | | 1,2 | K/W |





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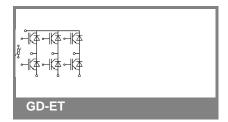
Typical Applications*

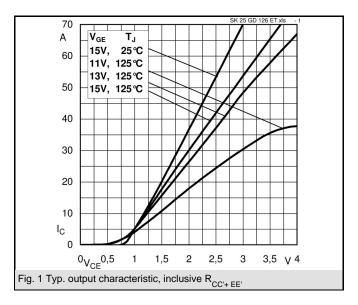
Inverter

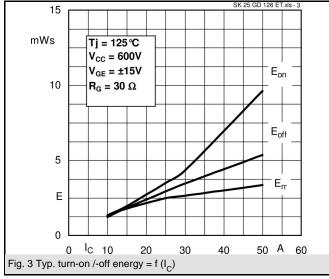
| Characteristics | | | | | | | |
|-----------------------|--|---|------|--------|------|------------------|--|
| Symbol | Conditions | | min. | typ. | max. | Units | |
| Inverse D | iode | | | | | | |
| $V_F = V_{EC}$ | I_{Fnom} = 25 A; V_{GE} = 0 V | $T_j = 25 ^{\circ}C_{\text{chiplev.}}$ | | 1,8 | | V | |
| | | $T_j = 125 ^{\circ}C_{chiplev.}$ | | 1,8 | | V | |
| V _{F0} | | T _j = 25 °C | | 1 | 1,1 | V | |
| | | T _j = 125 °C | | 0,8 | | V | |
| r _F | | T _j = 25 °C | | 32 | 42 | mΩ | |
| | | T _j = 125 °C | | 40 | | $\text{m}\Omega$ | |
| I _{RRM} | I _F = 25 A | T _j = 125 °C | | 31 | | Α | |
| Q_{rr} | di/dt = -950 A/µs | | | 5 | | μC | |
| E _{rr} | V _{CC} = 600V | | | 2,1 | | mJ | |
| R _{th(j-s)D} | per diode | | | | 1,9 | K/W | |
| M _s | to heat sink | | 2,25 | | 2,5 | Nm | |
| w | | | | 30 | | g | |
| Temperat | ure sensor | | | | | | |
| R ₁₀₀ | $T_s = 100^{\circ}C (R_{25} = 5k\Omega)$ | | | 493±5% | | Ω | |

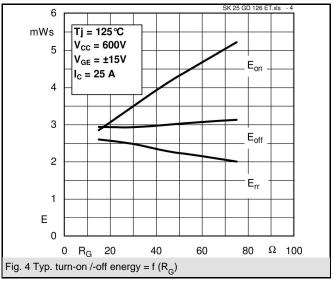
This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

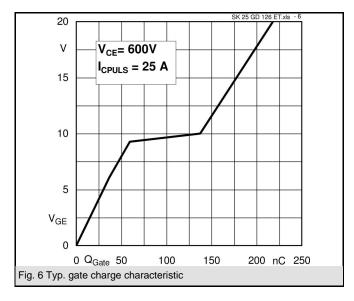
* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.

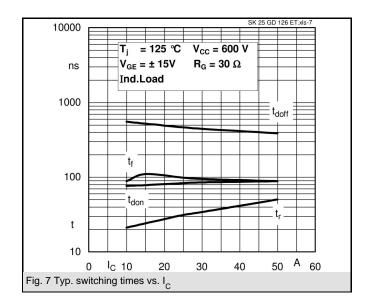


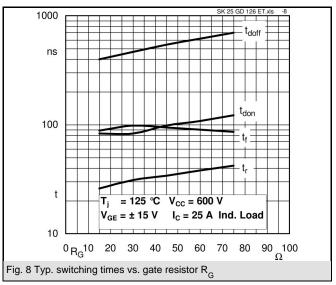


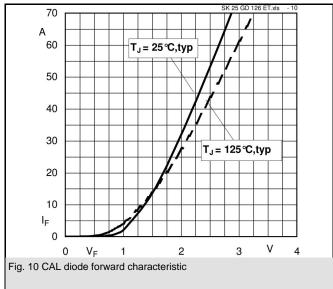












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